

Similarity and contrasts between thermodynamic properties at the critical point of liquid alkali metals and of electron-hole droplets

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(Dated:)

The recent experimental study by means of time-resolved luminescence measurements of an electron-hole liquid (EHL) in diamond by Shimano et al. [Phys. Rev. Lett. 88, 057404 (2002)] prompts us to compare and contrast critical temperature T_c and critical density n_c relations in liquid alkali metals with those in electron-hole liquids. The conclusion drawn is that these systems have similarities with regard to critical properties. In both cases the critical temperature is related to the cube root of the critical density. The existence of this relation is traced to Coulomb interactions and to systematic trends in the dielectric constant of the electron-hole systems. Finally a brief comparison between the alkalis and EHLs of the critical values for the compressibility ratio Z_c is also given.

PACS numbers: 71.35.Ee, 71.30.+h

Two of us¹ have been concerned in earlier work with the behavior of the thermodynamic quantities T_c , n_c and p_c , at the critical points of the liquid alkali metals. Relationships were shown to exist between critical temperature T_c and critical number density n_c for the liquid alkalis, the form anticipated in the earlier investigation of Chapman and March², namely

$$T_c n_c^{\frac{1}{3}} = \text{constant} \quad (1)$$

being confirmed in¹.

The present study has been prompted by the very recent experiment of Shimano et al.³, who report on the formation of an EHL⁴ with a high critical temperature $T_c = 165\text{K}$ in diamond, by means of time-resolved luminescence measurements under an intense femtosecond photoexcitation above the band gap. Then, by time-resolved spectral shape analysis, a very high carrier density $n_0 = 1.0 \cdot 10^{20}\text{cm}^{-3}$ at $T = 0$ is revealed, together with the high value of the critical temperature T_c already recorded above.

In addition to the important findings for the EHL in diamond, Shimano et al.³ comment in their introduction on the similarities between the physical properties of the EHL and liquefied metals. It is their comment which has motivated the present study, in which we compare and contrast EHL properties with those of the liquid alkali metals. The Eq. (1) above provides a natural starting point, but unfortunately while T_c is known for at least 5 EHLs, the same is not true for the critical density n_c .

However, prompted by the form (1), we have taken data from Ref.³, and have collected T_c and the zero temperature densities n_0 for 5 EHLs in Table 1 of the present paper. From these values, it can be readily shown that whereas T_c increases by a factor ~ 25 in going from Ge to diamond, the zero temperature quantity n_0 increases by

a factor $4 \cdot 10^2$. Due to the form (1), which we emphasize however contains the critical density n_c in the liquid alkalis, we have studied first the question as to whether T_c correlates with n_0 in the 5 EHLs referred to in Table 1. After some numerical investigation, we have constructed Fig. 1, which demonstrates beyond reasonable doubt that T_c and n_0 indeed correlate strongly. There is power law behavior between T_c and n_0 ; although the $\frac{1}{3}$ power in Eq. (1) must be modified (empirically to $\frac{1}{2}$: see caption to Fig. 1 and the further comments below). However, while Fig. 1 displays similarities of shape with Eq. (1) for the liquid alkalis, this equation contains the critical density n_c whereas for lack of experimental information, Fig. 1 correlates T_c with the zero temperature density n_0 .

In the absence of experimental information on n_c , we have sought a theoretical basis for bringing Eq. (1) and Fig. 1 into closer contact. We are considerably aided here by the work of Kalk et al.⁵. These authors observed picosecond electron-hole droplet formation in the indirect gap material $\text{Al}_x\text{Ga}_{1-x}\text{As}$. In the course of their exper-

	n_0 (cm^{-3})	T_c (K)	"
Ge	$2.5 \cdot 10^7$	6.7	16.0
Si	$3.3 \cdot 10^8$	24.5	12
GaP	$6 \cdot 10^8$	40	9.1
3C-SiC	$7.8 \cdot 10^8$	41	9.72
Diamond	$1.0 \cdot 10^{20}$	165	5.7

TABLE I: Values for the EHL number density n_0 at $T = 0$; the critical temperature T_c and the dielectric constant " in the indirect-gap semiconductors (Extracted from Table 1 of Ref. 3).

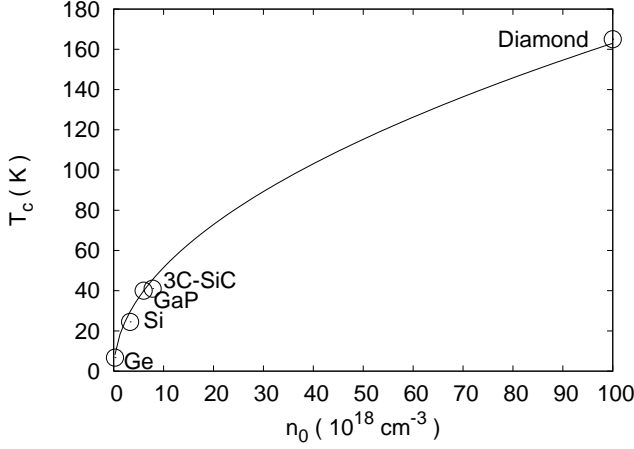


FIG. 1: Critical temperature T_c of EHL in the ve semiconductors referred to in Table 1 versus the (zero temperature) number density n_0 . The curve drawn is given by $T_c n_0^{\frac{1}{2}} = 16.3 \cdot 10^9 \text{ cm}^{\frac{3}{2}} \text{ K}$.

inental work, they refer to a 'scaling law'

$$\frac{n_c}{n_0} \propto 0.3 \quad (2)$$

with a reference to Forchelet al.⁶. Obviously, if we adopt this so-called 'scaling law', then Eq. (1) and the result from Fig. 1 come into intimate context, and the conclusion is that there is a different exponent, say generally denoted by β , for the relationship

$$T_c n_c^{\beta} = \text{constant} \quad (3)$$

with $\beta = \frac{1}{3}$ for the 5 alkalis and $\frac{1}{2}$ from Fig. 1 and Eq. (2) for the EHLs. Already, Chapman and March² had noted the totally different critical behavior for liquid alkali metals compared with condensed rare gases, for the latter case the exponent β being $\frac{1}{2}$.

As this brief report was nearing completion, we became aware of two further contributions. In the first of these, written more than 20 years ago by Reinecke and Ying⁷, the authors had anticipated a relation $T_c n_c^{\frac{1}{2}} = \text{constant}$. This is the more remarkable because it can be seen from the present Fig. 1 that the 'diamond' point of Shimano et al.³ is crucial to fitting the parabolic form, and allowing the above constant to be made wholly quantitative. The writers who anticipated the parabolic relation, however, went on to express doubts as to whether such a relation had any fundamental basis. This leads us to the second contribution referred to above: that of Likalter⁸.

Likalter studies what he emphasizes is the limiting situation of the EHL in which the hole mass $m_h \rightarrow m_e$; the electron mass. He then gives individual formulae for the critical constants T_c and n_c discussed above, and also for the critical pressure p_c . Our interest in Likalter's formulae is to expose relations between these critical constants which can then be compared and contrasted with known results for the alkali metals.

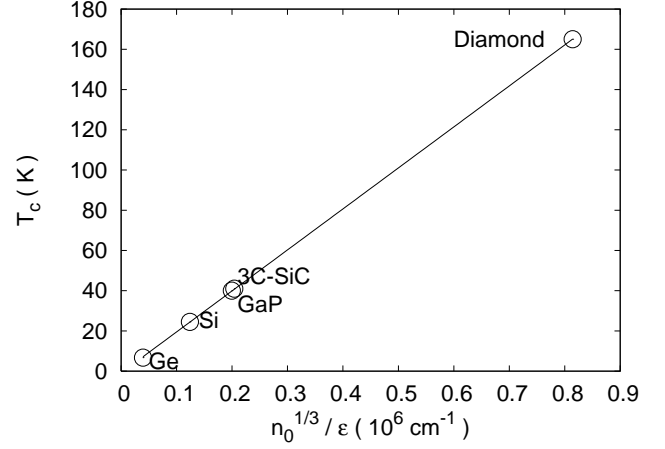


FIG. 2: Critical temperature T_c of the EHL of ve semiconductors referred to in Table 1 versus $\frac{n_0^{\frac{1}{3}}}{\epsilon}$, where n_0 is the number density of the EHL at $T = 0$ and ϵ the dielectric constant.

The first $T_c\{n_c$ relation which follows from Likalter's model is

$$T_c = \frac{4}{7} \cdot \frac{4}{3} \cdot \frac{1}{2} \cdot \frac{e^2}{n_c} \cdot \frac{n_c^{1/3}}{\epsilon} \quad (4)$$

where ϵ is a renormalized Madelung constant, given by Likalter as 0.55. This formula differs qualitatively from the fluid metals finding of Chapman and March² by the dielectric constant ϵ of the semiconductors appearing in the denominator. The limiting prediction of Eq. (4) deduced from Likalter's model will now be brought into close contact with the plot in Fig. 1. Thus in Fig. 2 we have used the data from Table 1, including the experimental dielectric constant values recorded in the final column, to plot T_c vs. $\frac{n_0^{\frac{1}{3}}}{\epsilon}$. There is clearly a linear relation as predicted by Likalter's model. Accepting the scaling relation (2), the parabolic fit of the data in Fig. 1 can be reconciled with the linearity of Fig. 2 provided ϵ and n_0 are related, of course approximately, by a $\frac{1}{6}$ power law. However, at present we have no fundamental justification for a relation $\epsilon n_0^{\frac{1}{6}} = \text{constant}$, because, at least in principle, such a formula could contain the binding energy of excitons, or the effective electron mass.

Returning to the similarities and differences from the fluid metals, we have also employed Likalter's individual formulae for T_c , n_c and p_c to calculate the so called compressibility ratio Z_c defined as

$$Z_c = \frac{p_c}{n_c k_B T_c} \quad (5)$$

which was studied in detail for the alkali metals in Ref.¹. The limiting formulae (for $m_h \rightarrow m_e$) then lead to the result

$$Z_c = \frac{7}{24} \quad (6)$$

This is near to the value for the heavier alkalis, 0.217 for Rb and 0.203 for Cs, but there is a wide variation through the alkali liquids, Li having a value of 0.064. The value in Eq. (6) is not so much smaller than the prediction from the van der Waals equation of state prediction, namely $3=8^9$.

The conclusion is firstly that there are some interesting similarities between the EHLs and the liquid alkali metals with regard to critical properties. In both cases T_c is related to $n_c^{1/3}$, which reflects the fingerprints of Coulomb interactions. For the EHL however, in the limiting case studied by Likalter⁸ where $m_h = m_e$; this quantity $n_c^{1/3}$ is divided by the dielectric constant ϵ of the semiconductor.

tors, high for Si and considerably reduced for diamond. Secondly, the limiting formulae of Likalter for T_c , n_c and p_c are shown to yield the constant critical compressibility ratio Z_c in Eq. (6), in contrast to the wide spread of values of Z_c in the liquid alkalis.

N.H.M. wishes to acknowledge some financial support from the Francoqui Foundation. Thanks are also due to the Executive Director, Professor L. Eyckmanns, for his help and encouragement. G.G.N.A. thanks the University of Antwerp (RUCA) for much hospitality. Finally, the authors wish to acknowledge the constructive comments made by two referees, which have enabled us to improve the presentation of this Report.

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